TCA9517 Level-Shifting I²C Bus Repeater

1 Features

- Two-Channel Bidirectional Buffer
- I²C Bus and SMBus Compatible
- Operating Supply Voltage Range of 0.9 V to 5.5 V on A-side
- Operating Supply Voltage Range of 2.7 V to 5.5 V on B-side
- Voltage-Level Translation From 0.9 V - 5.5 V to 2.7 V - 5.5 V
- Footprint and Functional Replacement for PCA9515B
- Active-High Repeater-Enable Input
- Open-Drain I²C I/O
- 5.5-V Tolerant I²C and Enable Input Support Mixed-Mode Signal Operation
- Accommodates Standard Mode and Fast Mode I²C Devices and Multiple Masters
- High-Impedance I²C Pins When Powered-Off
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 5500 V Human-Body Model (A114-A)
  - 200 V Machine Model (A115-A)
  - 1000 V Charged-Device Model (C101)

2 Applications

- Servers
- Routers (Telecom Switching Equipment)
- Industrial Equipment
- Products with Many I²C Slaves and/or Long PCB Traces

3 Description

The TCA9517 is a bidirectional buffer with level shifting capabilities for I²C and SMBus systems. It provides bidirectional voltage-level translation (up-translation/down-translation) between low voltages (down to 0.9 V) and higher voltages (2.7 V to 5.5 V) in mixed-mode applications. This device enables I²C and SMBus systems to be extended without degradation of performance, even during level shifting.

The TCA9517 buffers both the serial data (SDA) and the serial clock (SCL) signals on the I²C bus, thus allowing two buses of up to 400-pF bus capacitance to be connected in an I²C application.

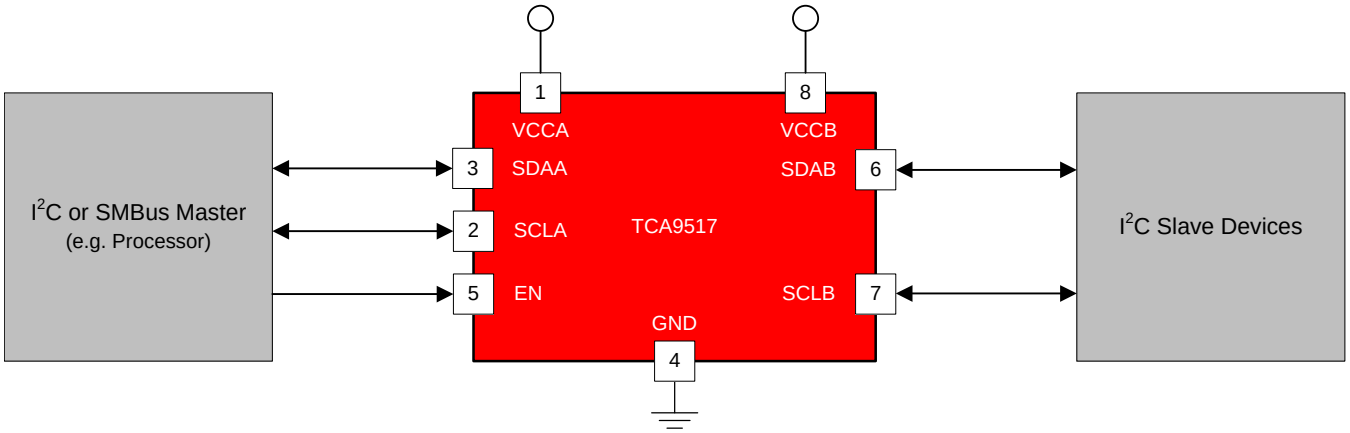
The TCA9517 has two types of drivers: A-side drivers and B-side drivers. All inputs and I/Os are over-voltage tolerant to 5.5 V, even when the device is unpowered (V_{CCB} and/or V_{CCA} = 0 V).

Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TCA9517	VSSOP (8)	3.00 mm × 3.00 mm
	SOIC (8)	4.90 mm x 3.91 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (May 2013) to Revision C — **Page**

- Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section ... 1
- Removed Ordering Information table. ... 3

Changes from Revision A (April 2013) to Revision B — **Page**

- Updated the TOP-SIDE MARKING column of the ORDERING INFORMATION TABLE. ... 1

Changes from Original (December 2012) to Revision A — **Page**

- Added D package to document. ... 1
- Updated the TOP-SIDE MARKING column of the ORDERING INFORMATION TABLE. ... 1

5 Description (continued)

The type of buffer design on the B-side prevents it from being used in series with devices which use static voltage offset. This is because these devices do not recognize buffered low signals as a valid low and do not propagate it as a buffered low again.

The B-side drivers operate from 2.7 V to 5.5 V. The output low level for this internal buffer is approximately 0.5 V, but the input voltage must be 70 mV or more below the output low level when the output internally is driven low. The higher-voltage low signal is called a buffered low. When the B-side I/O is driven low internally, the low is not recognized as a low by the input. This feature prevents a lockup condition from occurring when the input low condition is released.

The A-side drivers operate from 0.9 V to 5.5 V and drive more current. They do not require the buffered low feature (or the static offset voltage). This means that a low signal on the B-side translates to a nearly 0 V low on the A-side, which accommodates smaller voltage swings of lower-voltage logic. The output pulldown on the A-side drives a hard low, and the input level is set at $0.3 \times V_{CCA}$ to accommodate the need for a lower low level in systems where the low-voltage-side supply voltage is as low as 0.9 V.

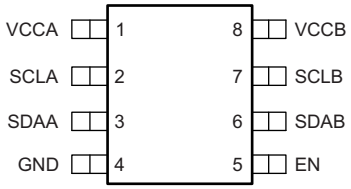
The A-side of two or more TCA9517 s can be connected together, allowing many topographies (See Figure 8 and Figure 9), with the A-side as the common bus. Also, the A-side can be connected directly to any other buffer with static- or dynamic-offset voltage. Multiple TCA9517 s can be connected in series, A-side to B-side, with no buildup in offset voltage and with only time-of-flight delays to consider. The TCA9517 cannot be connected B-side to B-side, because of the buffered low voltage from the B-side. The B-side cannot be connected to a device with rise time accelerators.

VCCA is only used to provide the $0.3 \times V_{CCA}$ reference to the A-side input comparators and for the power-good-detect circuit. The TCA9517 logic and all I/Os are powered by the VCCB pin.

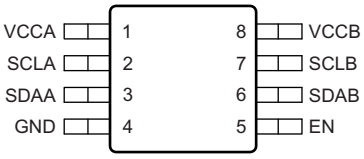
As with the standard I^2C system, pullup resistors are required to provide the logic-high levels on the buffered bus. The TCA9517 has standard open-drain configuration of the I^2C bus. The size of these pullup resistors depends on the system, but each side of the repeater must have a pullup resistor. The device is designed to work with Standard mode and Fast mode I^2C devices in addition to SMBus devices. Standard mode I^2C devices only specify 3 mA in a generic I^2C system, where Standard mode devices and multiple masters are possible. Under certain conditions, higher termination currents can be used.

6 Pin Configuration and Functions

D Packages
8-Pin SOIC
Top View



DGK Package
8-Pin VSSOP
Top View



Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	VCCA	Supply	A-side supply voltage (0.9 V to 5.5 V)
2	SCLA	Input/Output	Serial clock bus, A-side. Connect to V_{CCA} through a pull-up resistor. If unused, connect directly to ground.
3	SDAA	Input/Output	Serial data bus, A-side. Connect to V_{CCA} through a pull-up resistor. If unused, connect directly to ground.
4	GND	Ground	Ground
5	EN	Input	Active-high repeater enable input
6	SDAB	Input/Output	Serial data bus, B-side. Connect to V_{CCB} through a pull-up resistor. If unused, connect directly to ground.
7	SCLB	Input/Output	Serial clock bus, B-side. Connect to V_{CCB} through a pull-up resistor. If unused, connect directly to ground.
8	VCCB	Supply	B-side and device supply voltage (2.7 V to 5.5 V)

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CCB}	Supply voltage range		–0.5	7	V
V_{CCA}	Supply voltage range		–0.5	7	V
V_I	Enable input voltage range(2)		–0.5	7	V
$V_{I/O}$	I^2C bus voltage range(2)		–0.5	7	V
I_{IK}	Input clamp current	$V_I < 0$		–50	mA
I_{OK}	Output clamp current	$V_O < 0$		–50	
I_O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±5500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	
		Machine model (A115-A)	±200	

(1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V_{CCA}	Supply voltage, A-side bus		0.9 (1)	5.5	V
V_{CCB}	Supply voltage, B-side bus		2.7	5.5	V
V_{IH}	High-level input voltage	SDAA, SCLA	0.7 × V_{CCA}	5.5	V
		SDAB, SCLB	0.7 × V_{CCB}	5.5	
		EN	0.7 × V_{CCB}	5.5	
V_{IL}	Low-level input voltage	SDAA, SCLA		0.3 × V_{CCA}	V
		SDAB, SCLB (2)		0.3 × V_{CCB}	
		EN		0.3 × V_{CCB}	
I_{OL}	Low-level output current			6	mA
T_A	Operating free-air temperature		–40	85	°C

(1) Low-level supply voltage
(2) V_{IL} specification is for the first low level seen by the SDAB and SCLB lines. V_{ILc} is for the second and subsequent low levels seen by the SDAB and SCLB lines. See *V_{ILC} and Pullup Resistor Sizing* for V_{ILC} application information

7.4 Thermal Information

THERMAL METRIC (1)		TCA9517		UNIT
		DGK (VSSOP)	D (SOIC)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	187.6	133.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	59.3	87.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	108.6	74.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	3.4	36.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	106.9	73.7	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

7.5 Electrical Characteristics

V_{CCB} = 2.7 V to 5.5 V, GND = 0 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER			TEST CONDITIONS	V_{CCB}	MIN	TYP	MAX	UNIT
V_{IK}	Input clamp voltage		I_I = –18 mA	2.7 V to 5.5 V			–1.2	V
V_{OL}	Low-level output voltage	SDAB, SCLB	I_{OL} = 100 µA or 6 mA, V_{ILA} = V_{ILB} = 0 V	2.7 V to 5.5 V	0.45	0.52	0.6	V
		SDAA, SCLA	I_{OL} = 6 mA			0.1	0.2	
V_{OL} – V_{ILc}	Low-level input voltage below low-level output voltage	SDAB, SCLB	ensured by design	2.7 V to 5.5 V		70		mV
V_{ILC}	SDA and SCL low-level input voltage contention	SDAB, SCLB		2.7 V to 5.5 V		0.4		V
I_{CC}	Quiescent supply current for V_{CCA}		Both channels low, SDAA = SCLA = GND and SDAB = SCLB = open, or SDAA = SCLA = open and SDAB = SCLB = GND				1	mA
I_{CC}	Quiescent supply current		Both channels high, SDAA = SCLA = V_{CCA} and SDAB = SCLB = V_{CCB} and EN = V_{CCB}	5.5 V		1.5	5	mA
			Both channels low, SDAA = SCLA = GND and SDAB = SCLB = open			1.5	5	
			In contention, SDAA = SCLA = GND and SDAB = SCLB = GND			3	5	
I_I	Input leakage current	SDAB, SCLB	V_I = V_{CCB}	2.7 V to 5.5 V			±1	µA
			V_I = 0.2 V				10	
		SDAA, SCLA	V_I = V_{CCB}				±1	
			V_I = 0.2 V				10	
		EN	V_I = V_{CCB}				±1	
			V_I = 0.2 V			–10	–30	
I_{OH}	High-level output leakage current	SDAB, SCLB	V_O = 3.6 V	2.7 V to 5.5 V			10	µA
		SDAA, SCLA					10	
C_I	Input capacitance	EN	V_I = 3 V or 0 V	3.3 V		6	10	pF
		SCLA, SCLB	V_I = 3 V or 0 V	3.3 V		8	13	
				0 V		7	11	
C_{IO}	Input/output capacitance	SDAA, SDAB	V_I = 3 V or 0 V	3.3 V		8	13	pF
				0 V		7	11	

7.6 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
t_{su}	Setup time, EN high before Start condition(1)	100		ns
t_h	Hold time, EN high after Stop condition(1)	100		ns

(1) EN should change state only when the global bus and the repeater port are in an idle state.

7.7 I²C Interface Switching Characteristics

V_{CCB} = 2.7 V to 5.5 V, GND = 0 V, T_A = –40°C to 85°C (unless otherwise noted)(1) (2)

PARAMETER			FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP(3)	MAX	UNIT
t_{PLZ}	Propagation delay		SDAB, SCLB(4) (see Figure 6)	SDAA, SCLA(4) (see Figure 6)		80	141	250	ns
			SDAA, SCLA(5) (see Figure 5)	SDAB, SCLB(5) (see Figure 5)		25	74	110	
t_{PZL}	Propagation delay		SDAB, SCLB	SDAA, SCLA	V_{CCA} ≤ 2.7 V (see Figure 4)	30	76(6)	110	ns
					V_{CCA} ≥ 3 V (see Figure 4)	10	86	230	
			SDAA, SCLA(5) (see Figure 5)	SDAB, SCLB(5) (see Figure 5)		60	107	230	
t_{TLH}	Transition time	B-side to A side	80%	20%	V_{CCA} ≤ 2.7 V (see Figure 5)	10	12	15	ns
					V_{CCA} ≥ 3 V (see Figure 5)	40	42	45	
		A side to B-side (see Figure 4)				110	125	140	
t_{THL}	Transition time	B-side to A side	80%	20%	V_{CCA} ≤ 2.7 V (see Figure 5)	1	52(6)	105	ns
					V_{CCA} ≥ 3 V (see Figure 5)	20	67	175	
		A side to B-side (see Figure 4)				30	48	90	

(1) Times are specified with loads of 1.35-kΩ pull-up resistance and 50-pF load capacitance on the B-side and 167-Ω pull-up and 57-pF load capacitance on the A side. Different load resistance and capacitance alter the RC time constant, thereby changing the propagation delay and transition times.
(2) pull-up voltages are V_{CCA} on the A side and V_{CCB} on the B-side.
(3) Typical values were measured with V_{CCA} = V_{CCB} = 3.3 V at T_A = 25°C, unless otherwise noted.
(4) The t_{PLH} delay data from B to A side is measured at 0.4 V on the B-side to 0.5 V_{CCA} on the A side when V_{CCA} is less than 2 V, and 1.5 V on the A side if V_{CCA} is greater than 2 V.
(5) The proportional delay data from A to B-side is measured at 0.3 V_{CCA} on the A side to 1.5 V on the B-side.
(6) Typical value measured with V_{CCA} = 2.7 V at T_A = 25°C

7.8 Typical Characteristics

V_{CCA} = 0.9 V, V_{CCB} = 2.7 V

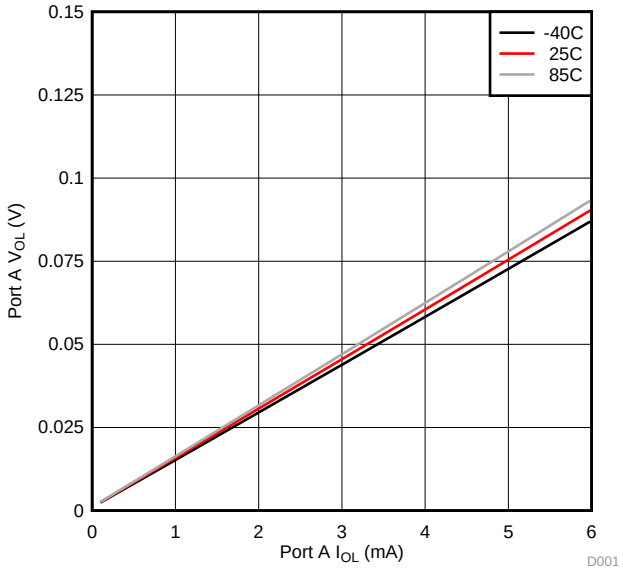


Figure 1. Port A V_{OL} vs I_{OL}

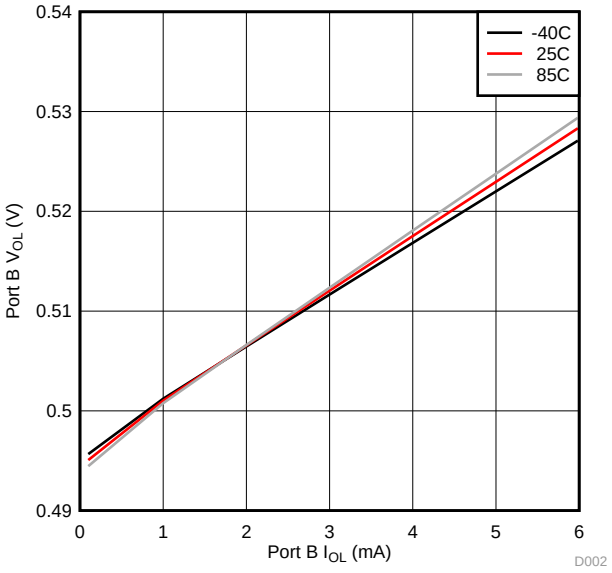
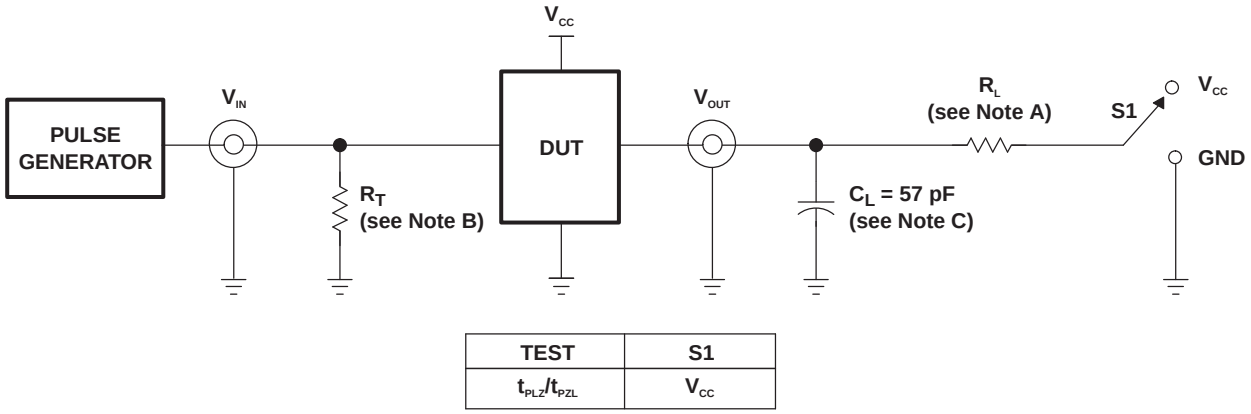


Figure 2. Port B V_{OL} vs I_{OL}

8 Parameter Measurement Information



TEST	S1
t_{PLZ}/t_{PZL}	V_{CC}

TEST CIRCUIT FOR OPEN-DRAIN OUTPUT

A. R_L = 167 Ω (0.9 V to 2.7 V) and R_L = 450 Ω (3.0 V to 5.5 V) on the A side and 1.35 kΩ on the B-side

B. R_T termination resistance should be equal to Z_{OUT} of pulse generators.

C. C_L includes probe and jig capacitance.

D. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, slew rate ≥ 1 V/ns.

E. The outputs are measured one at a time, with one transition per measurement.

F. t_{PLH} and t_{PHL} are the same as t_{pd}.

G. t_{PLZ} and t_{PHZ} are the same as t_{dis}.

H. t_{PZL} and t_{PZH} are the same as t_{en}.

Figure 3. Test Circuit

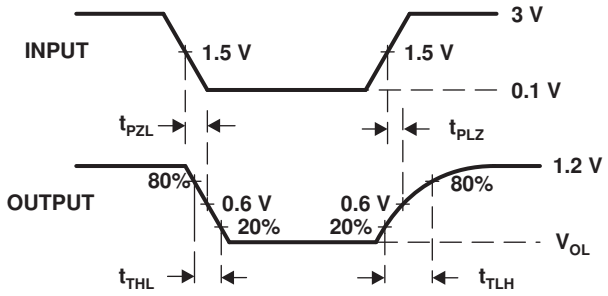


Figure 4. Waveform 1 – Propagation Delay and Transition Times for B-side to A-side

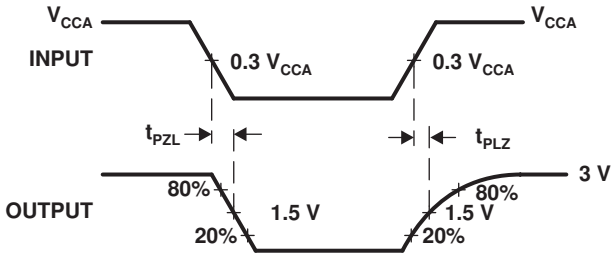


Figure 5. Waveform 2 – Propagation Delay and Transition Times for A-side to B-side

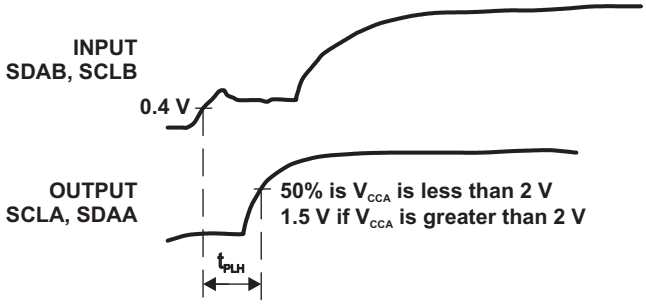


Figure 6. Waveform 3 – Propagation Delay for B-side to A-side

9 Detailed Description

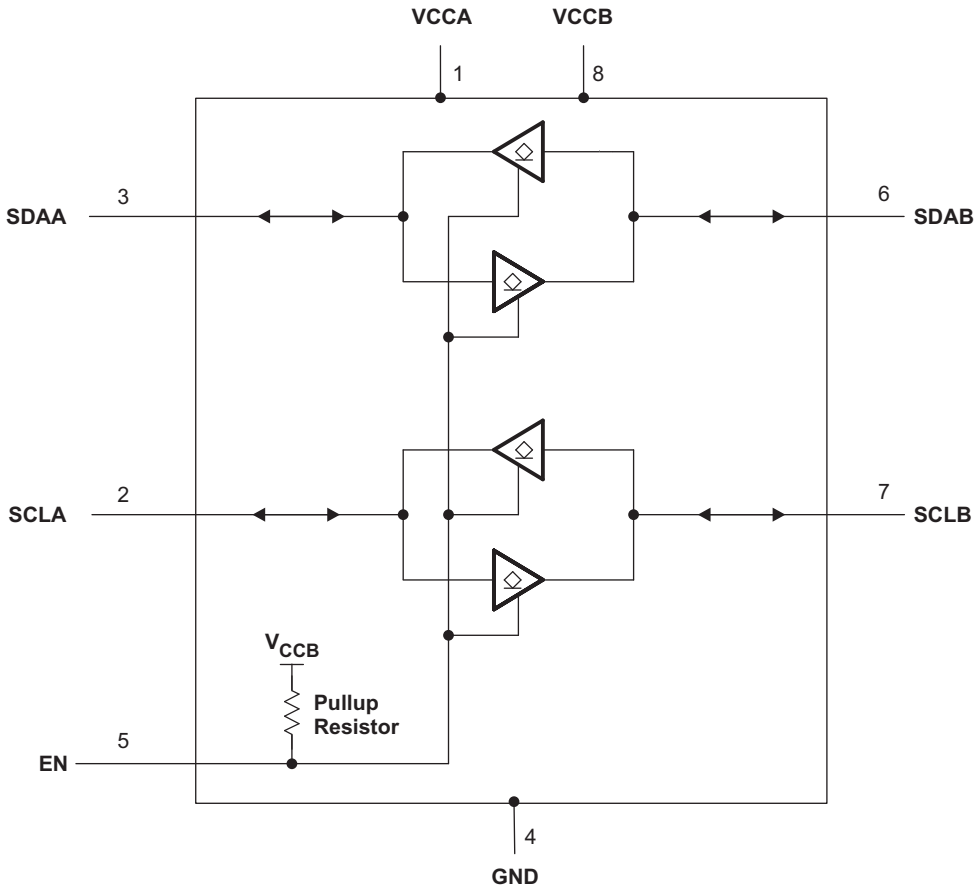
9.1 Overview

The TCA9517 is a bidirectional buffer with level shifting capabilities for I^2C and SMBus systems. It provides bidirectional voltage-level translation (up-translation/down-translation) between low voltages (down to 0.9 V) and higher voltages (2.7 V to 5.5 V) in mixed-mode applications. This device enables I^2C and SMBus systems to be extended without degradation of performance, even during level shifting.

The TCA9517 buffers both the serial data (SDA) and the serial clock (SCL) signals on the I^2C bus, thus allowing two buses of up to 400-pF bus capacitance to be connected in an I^2C application.

The TCA9517 has two types of drivers: A-side drivers and B-side drivers. All inputs and I/Os are over-voltage tolerant to 5.5 V, even when the device is unpowered (V_{CCB} and/or V_{CCA} = 0 V).

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Two-Channel Bidirectional Buffer

The TCA9517 is a two-channel bidirectional buffer with level-shifting capabilities

9.3.2 Active-High Repeater-Enable Input

The TCA9517 has an active-high enable (EN) input with an internal pull-up to V_{CCB}, which allows the user to select when the repeater is active. This can be used to isolate a badly behaved slave on power-up reset. The EN input should change state only when the global bus and repeater port are in an idle state, to prevent system failures.

9.3.3 V_{OL} B-Side Offset Voltage

The B-side drivers operate from 2.7 V to 5.5 V. The output low level for this internal buffer is approximately 0.5 V, but the input voltage must be 70 mV or more below the output low level when the output internally is driven low. The higher-voltage low signal is called a buffered low. When the B-side I/O is driven low internally, the low is not recognized as a low by the input. This feature prevents a lockup condition from occurring when the input low condition is released. This type of design prevents 2 B-side ports from being connected to each other.

9.3.4 Standard Mode and Fast Mode Support

The TCA9517 supports standard mode as well as fast mode I^2C. The maximum system operating frequency will depend on system design and the delays added by the repeater.

9.3.5 Clock Stretching Support

The TCA9517 can support clock stretching, but care needs to be taken to minimize the overshoot voltage presented during the hand-off between the slave and master. This is best done by increasing the pull-up resistor value.

9.4 Device Functional Modes

Table 1. Function Table

INPUT EN	FUNCTION
L	Outputs disabled
H	SDAA = SDAB SCLA = SCLB

10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

A typical application is shown in Figure 7. In this example, the system master is running on a 3.3 V I^2C bus, and the slave is connected to a 1.2 V I^2C bus. Both buses run at 400 kHz. Master devices can be placed on either bus.

The TCA9517 is 5-V tolerant, so it does not require any additional circuitry to translate between 0.9 V to 5.5 V bus voltages and 2.7 V to 5.5 V bus voltages.

When the A side of the TCA9517 is pulled low by a driver on the I^2C bus, a comparator detects the falling edge when it goes below 0.3 × V_{CCA} and causes the internal driver on the B-side to turn on, causing the B-side to pull down to about 0.5 V. When the B-side of the TCA9517 falls, first a CMOS hysteresis-type input detects the falling edge and causes the internal driver on the A side to turn on and pull the A-side pin down to ground. In order to illustrate what would be seen in a typical application, refer to Figure 9 and Figure 10. If the bus master in Figure 7 were to write to the slave through the TCA9517 , waveforms shown in Figure 9 would be observed on the A bus. This looks like a normal I^2C transmission, except that the high level may be as low as 0.9 V, and the turn on and turn off of the acknowledge signals are slightly delayed.

On the B-side bus of the TCA9517 , the clock and data lines would have a positive offset from ground equal to the V_{OL} of the TCA9517 . After the eighth clock pulse, the data line is pulled to the V_{OL} of the slave device, which is very close to ground in this example. At the end of the acknowledge, the level rises only to the low level set by the driver in the TCA9517 for a short delay, while the A-bus side rises above 0.3 × V_{CCA} and then continues high.

10.2 Typical Application

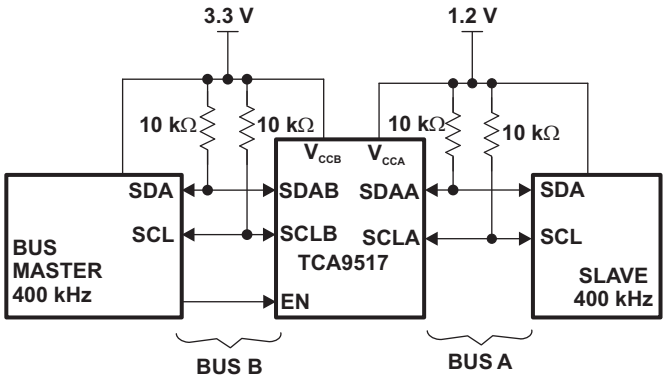


Figure 7. Typical Application Schematic

10.2.1 Design Requirements

For the level translating application, the following should be true:

- V_{CCA} = 0.9 V to 5.5 V
- V_{CCB} = 2.7 to 5.5 V
- $V_{CCA} < V_{CCB}$
- B-side ports must not be connected together

Typical Application (continued)

10.2.2 Detailed Design Procedure

10.2.2.1 Clock Stretching Support

The TCA9517 can support clock stretching, but care needs to be taken to minimize the overshoot voltage presented during the hand-off between the slave and master. This is best done by increasing the pull-up resistor value.

10.2.2.2 V_{ILC} and Pullup Resistor Sizing

For the TCA9517 to function correctly, all devices on the B-side must be able to pull the B-side below the voltage input low contention level (V_{ILC}). This means that the V_{OL} of any device on the B-side must be below 0.4 V.

V_{OL} of a device can be adjusted by changing the I_{OL} through the device which is set by the pull-up resistance value. The pull-up resistance on the B-side must be carefully selected to ensure that logic levels will be transferred correctly to the A-side.

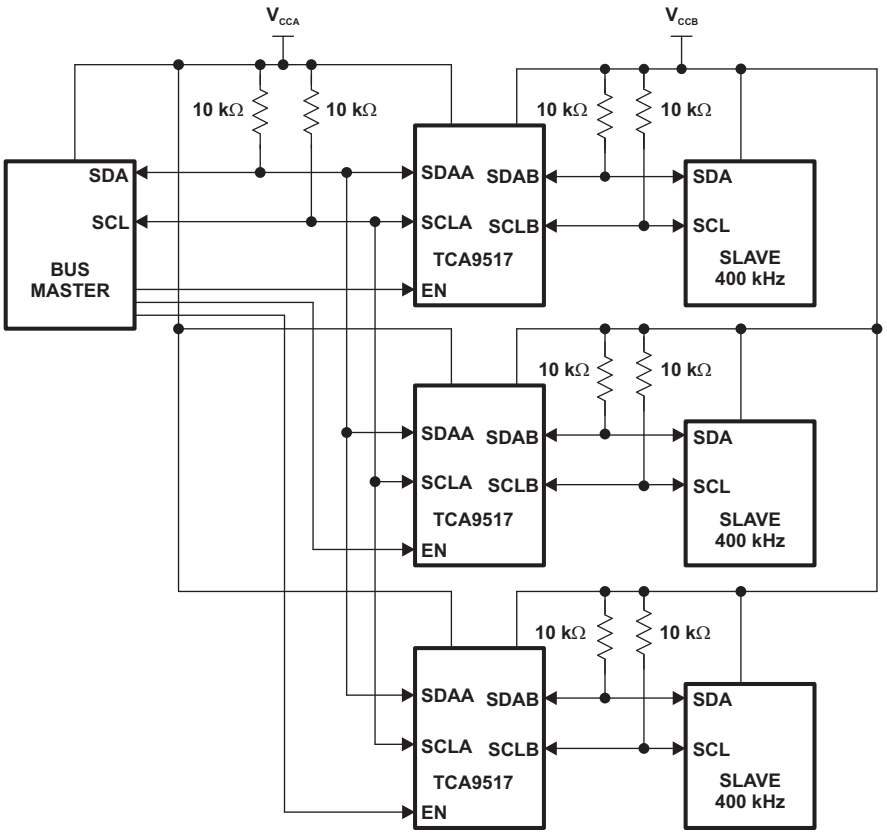


Figure 8. Typical Star Application

Multiple A sides of TCA9517 s can be connected in a star configuration, allowing all nodes to communicate with each other.

Typical Application (continued)

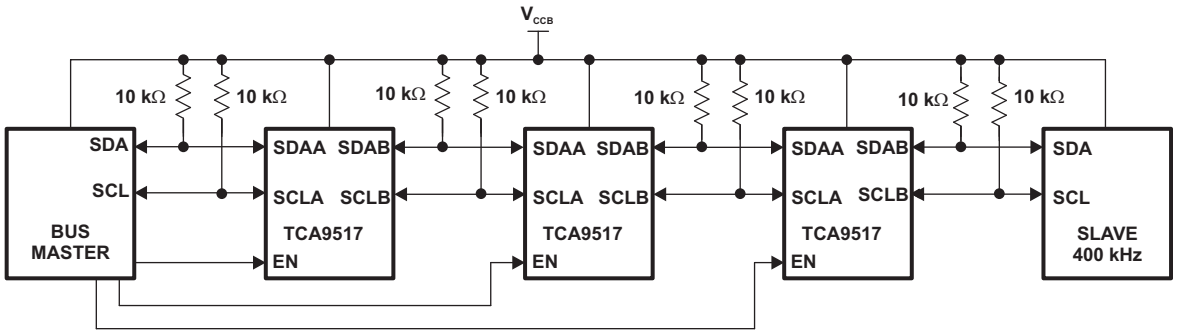


Figure 9. Typical Series Application

To further extend the I^2C bus for long traces/cables, multiple TCA9517 s can be connected in series as long as the A-side is connected to the B-side. I^2C bus slave devices can be connected to any of the bus segments. The number of devices that can be connected in series is limited by repeater delay/time-of-flight considerations on the maximum bus speed requirements.

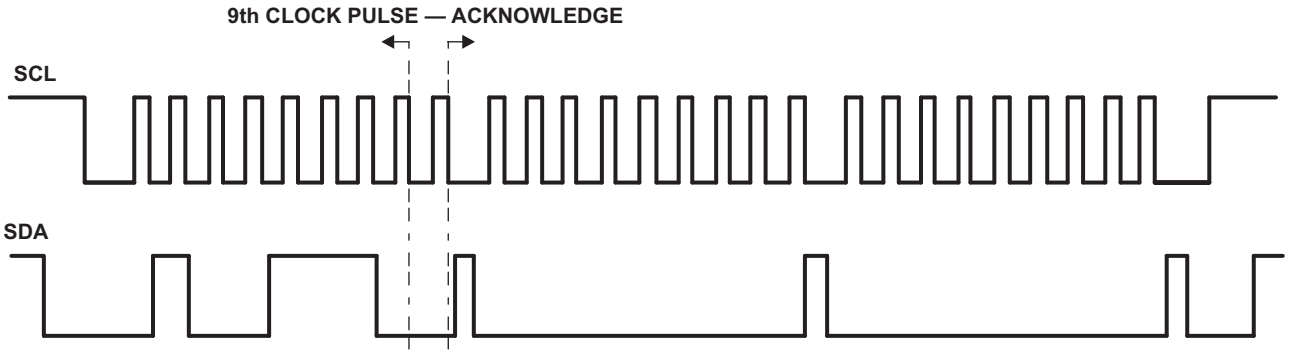


Figure 10. Bus A (0.9 V to 5.5 V Bus) Waveform

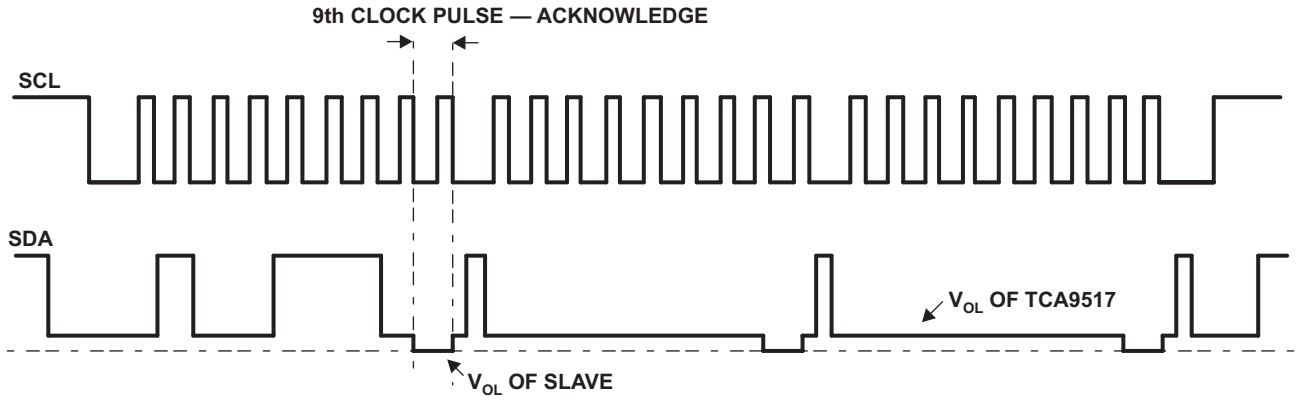


Figure 11. Bus B (2.7 V to 5.5 V Bus) Waveform

Typical Application (continued)

10.2.3 Application Curve

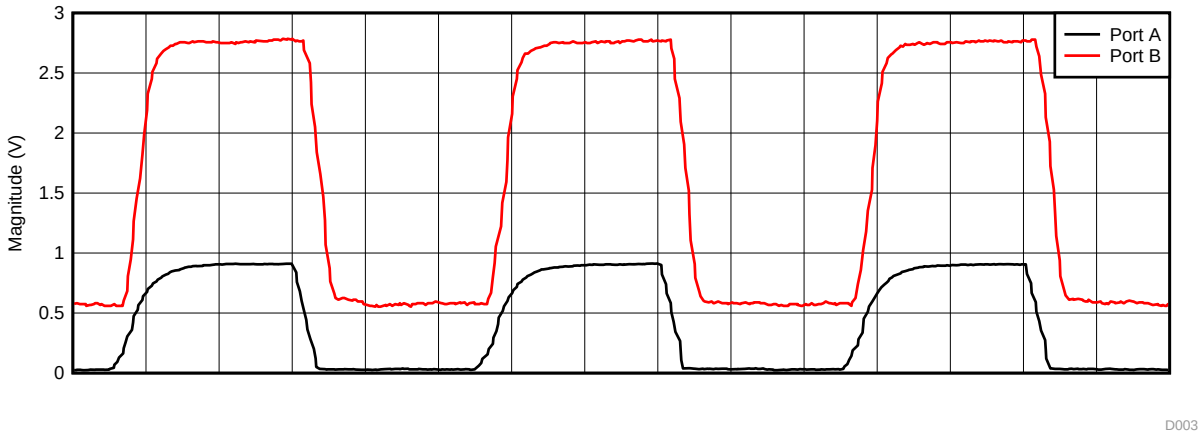


Figure 12. Voltage Translation at 400 kHz, V_{CCA} = 0.9 V, V_{CCB} = 2.7 V

11 Power Supply Recommendations

V_{CCB} and V_{CCA} can be applied in any sequence at power up. The TCA9517 includes a power-up circuit that keeps the output drivers turned off until V_{CCB} is above 2.5 V and the V_{CCA} is above 0.8 V. After power up and with the EN high, a low level on the A-side (below 0.3 × V_{CCA}) turns the corresponding B-side driver (either SDA or SCL) on and drives the B-side down to approximately 0.5 V. When the A-side rises above 0.3 × V_{CCA}, the B-side pull-down driver is turned off and the external pull-up resistor pulls the pin high. When the B-side falls first and goes below 0.3 × V_{CCB}, the A-side driver is turned on and the A-side pulls down to 0 V. The B-side pull-down is not enabled unless the B-side voltage goes below 0.4 V. If the B-side low voltage does not go below 0.5 V, the A-side driver turns off when the B-side voltage is above 0.7 × V_{CCB}. If the B-side low voltage goes below 0.4 V, the B-side pull-down driver is enabled, and the B-side is able to rise to only 0.5 V until the A-side rises above 0.3 × V_{CCA}.

TI recommends using a decoupling capacitor and placing it close to the VCCA and VCCB pins of a value of about 100 nF.

12 Layout

12.1 Layout Guidelines

There are no special layout procedures required for the TCA9517 .

It is recommended that the decoupling capacitors be placed as close to the VCC pins as possible.

12.2 Layout Example

Figure 13 shows an example layout of the DGK package.

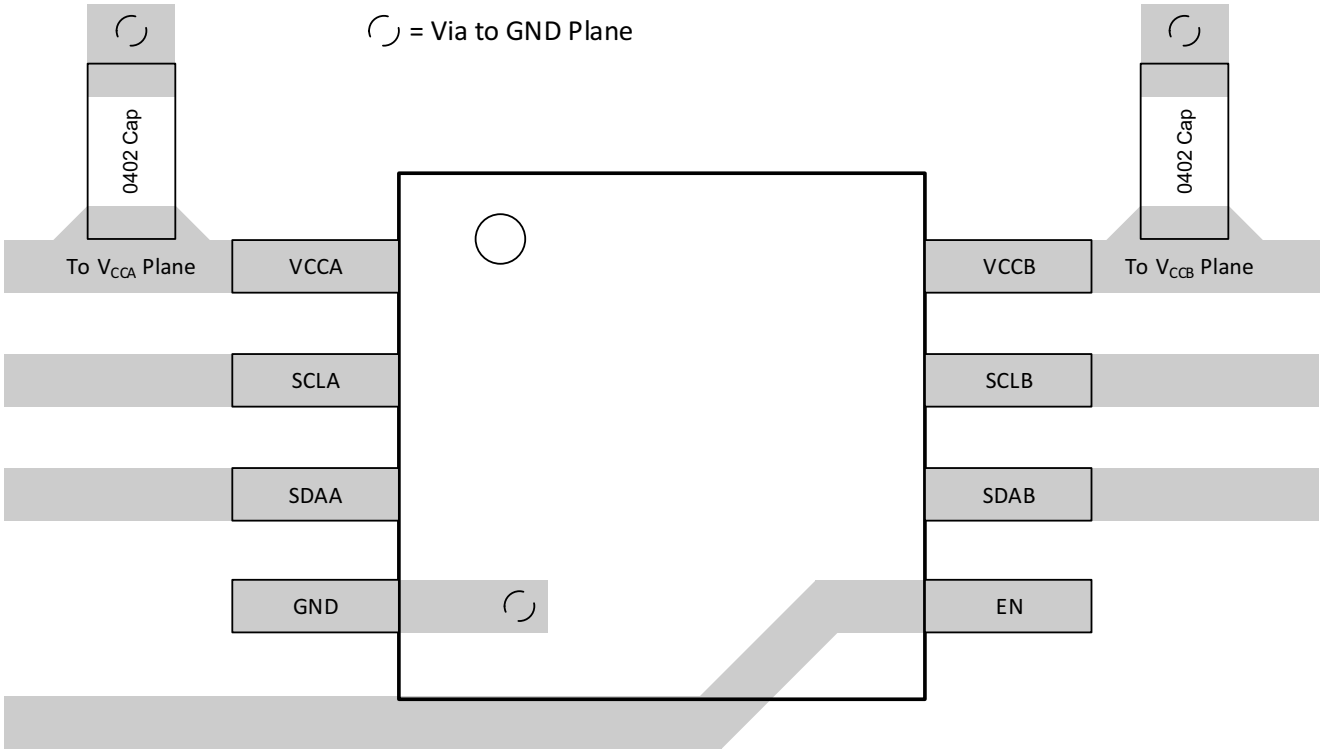


Figure 13. TCA9517A Layout Example

13 Device and Documentation Support

13.1 Community Resource

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.2 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TCA9517DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AYK	Samples
TCA9517DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	PW517	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

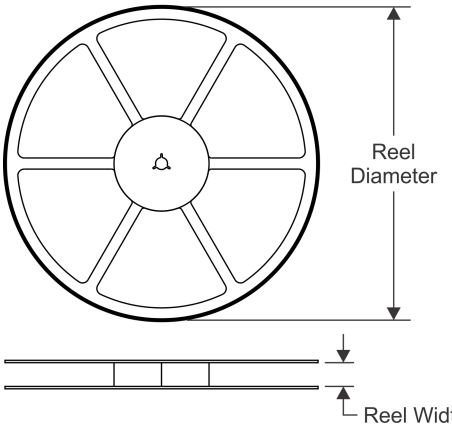
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

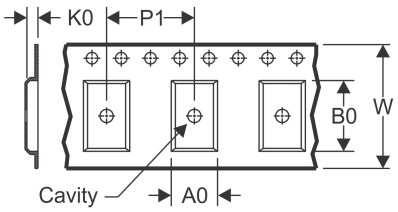
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

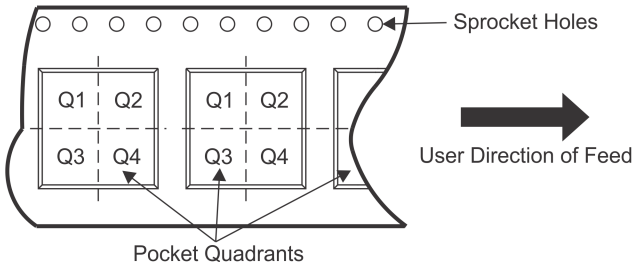


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

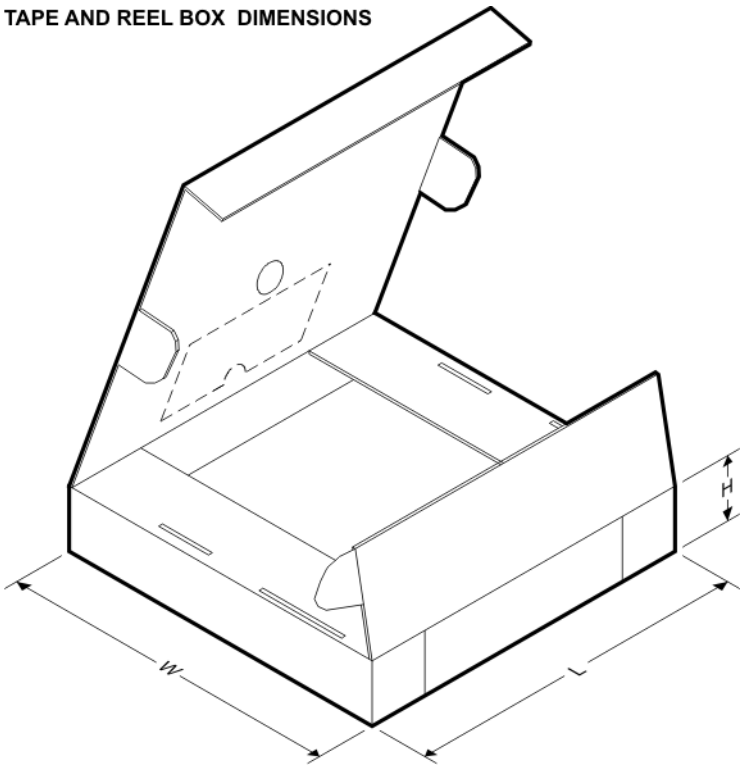
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCA9517DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TCA9517DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

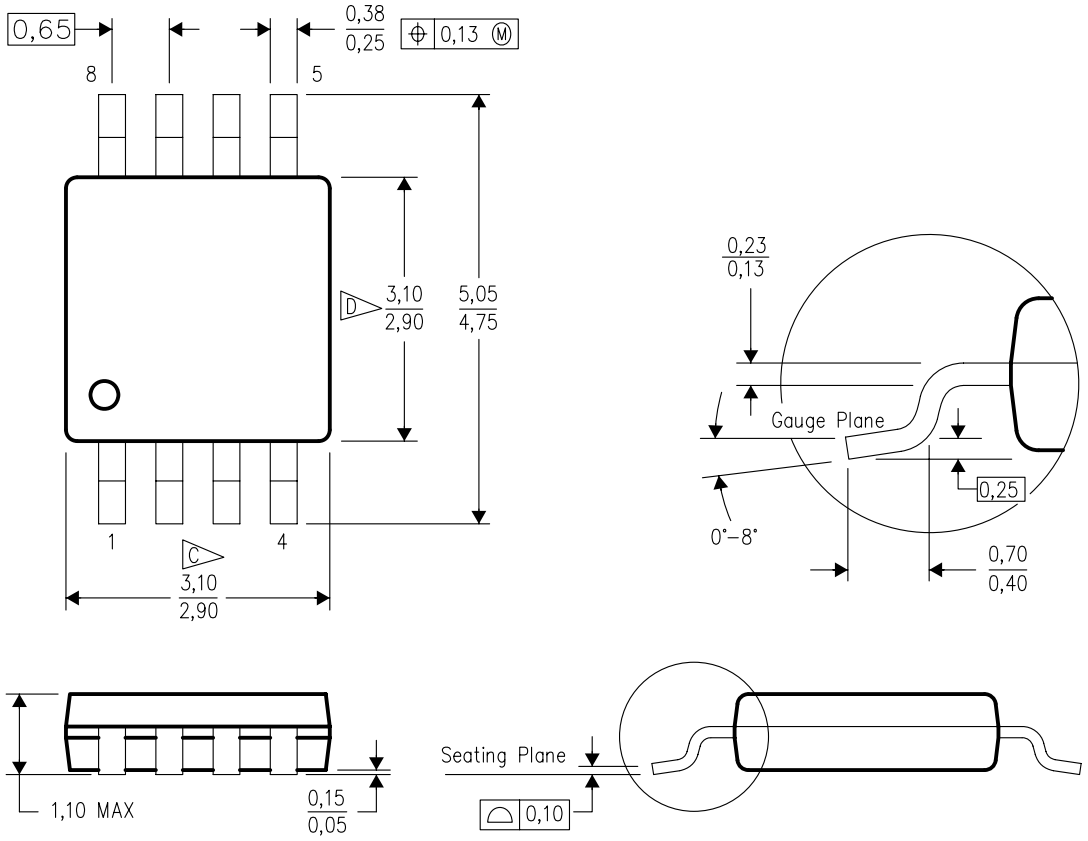
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCA9517DGKR	VSSOP	DGK	8	2500	364.0	364.0	27.0
TCA9517DR	SOIC	D	8	2500	340.5	338.1	20.6

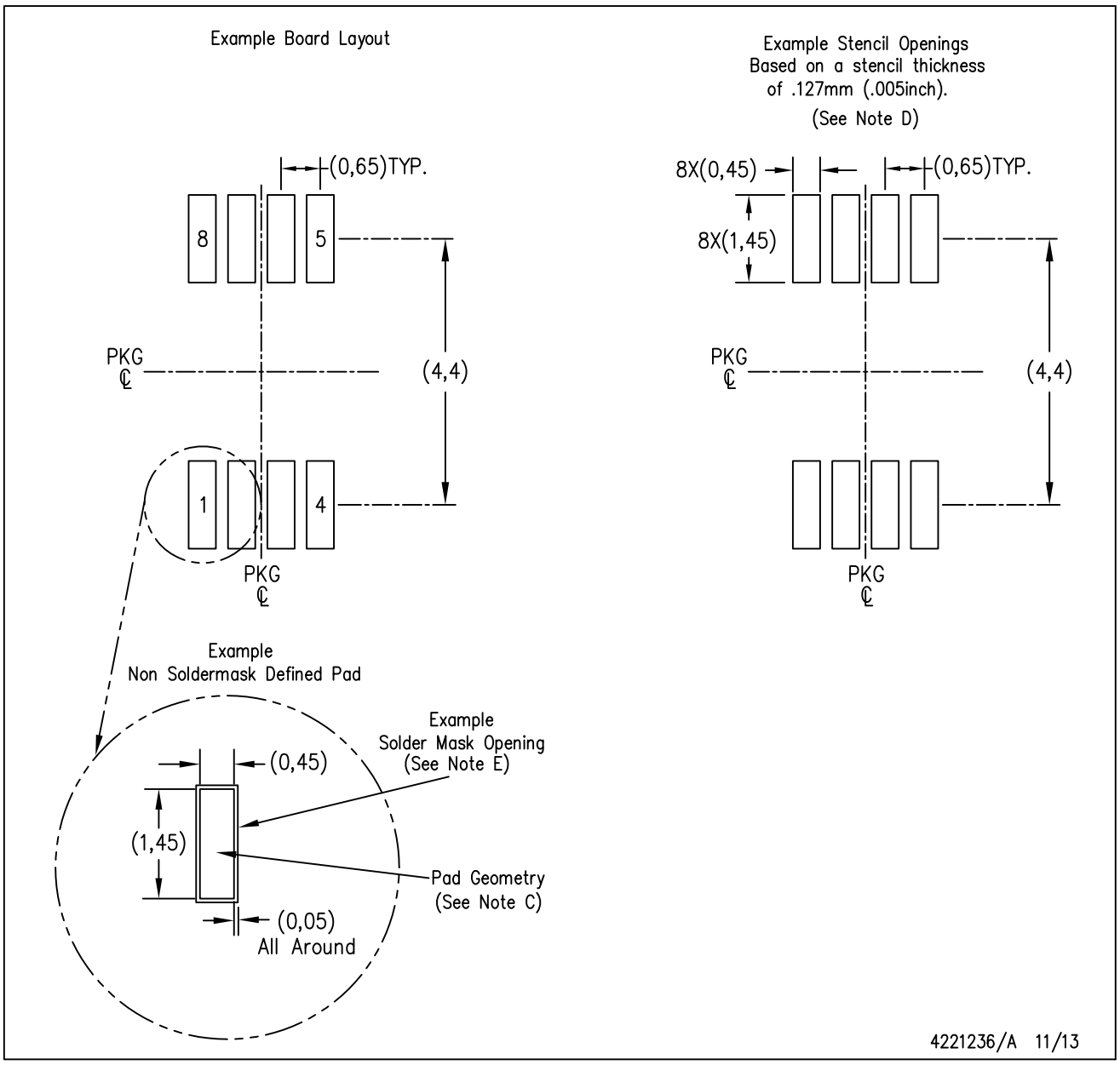
DGK (S–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



4073329/E 05/06

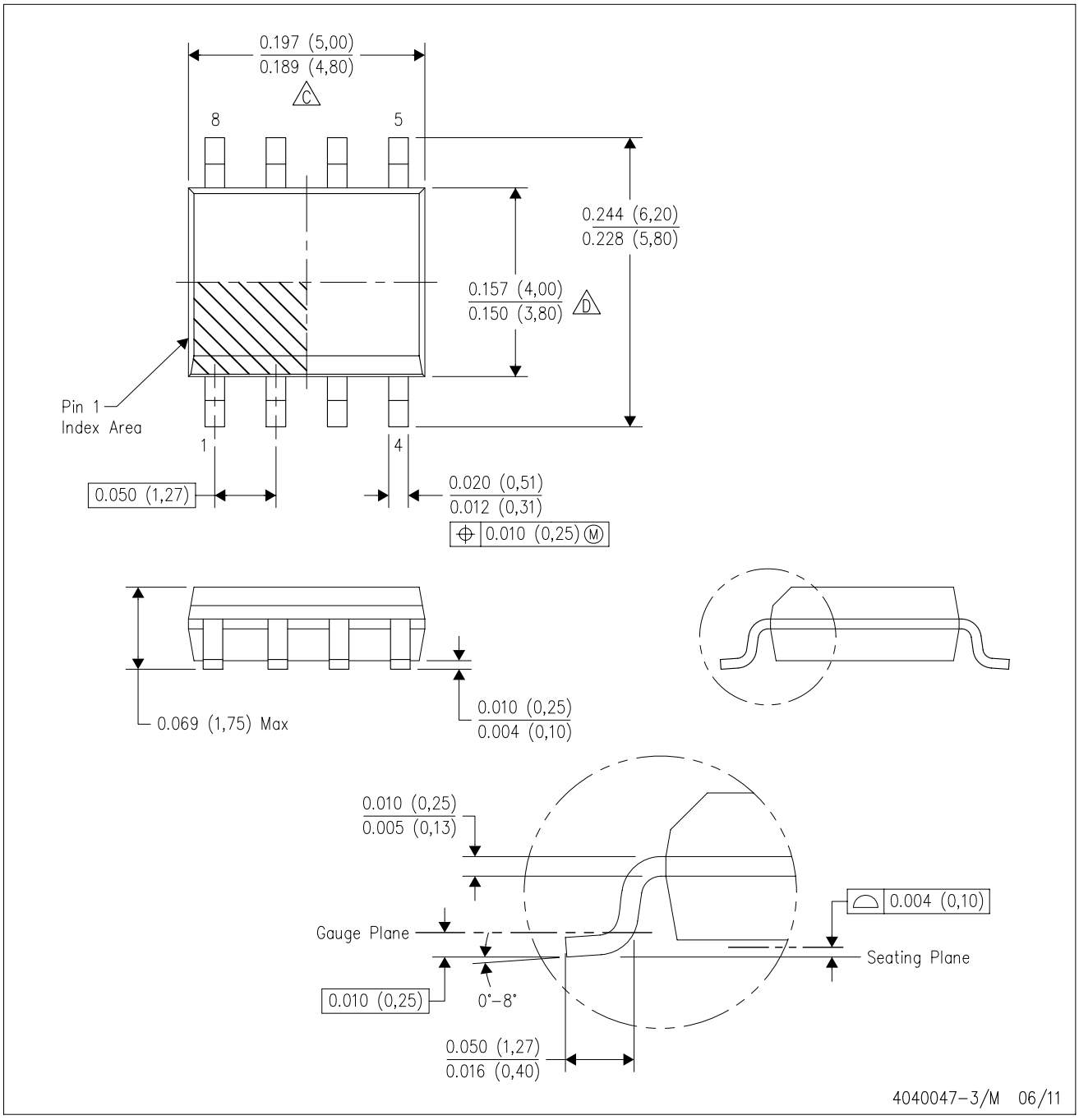
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
E. Falls within JEDEC MO–187 variation AA, except interlead flash.

DGK (S–PDSO–G8) PLASTIC SMALL OUTLINE PACKAGE



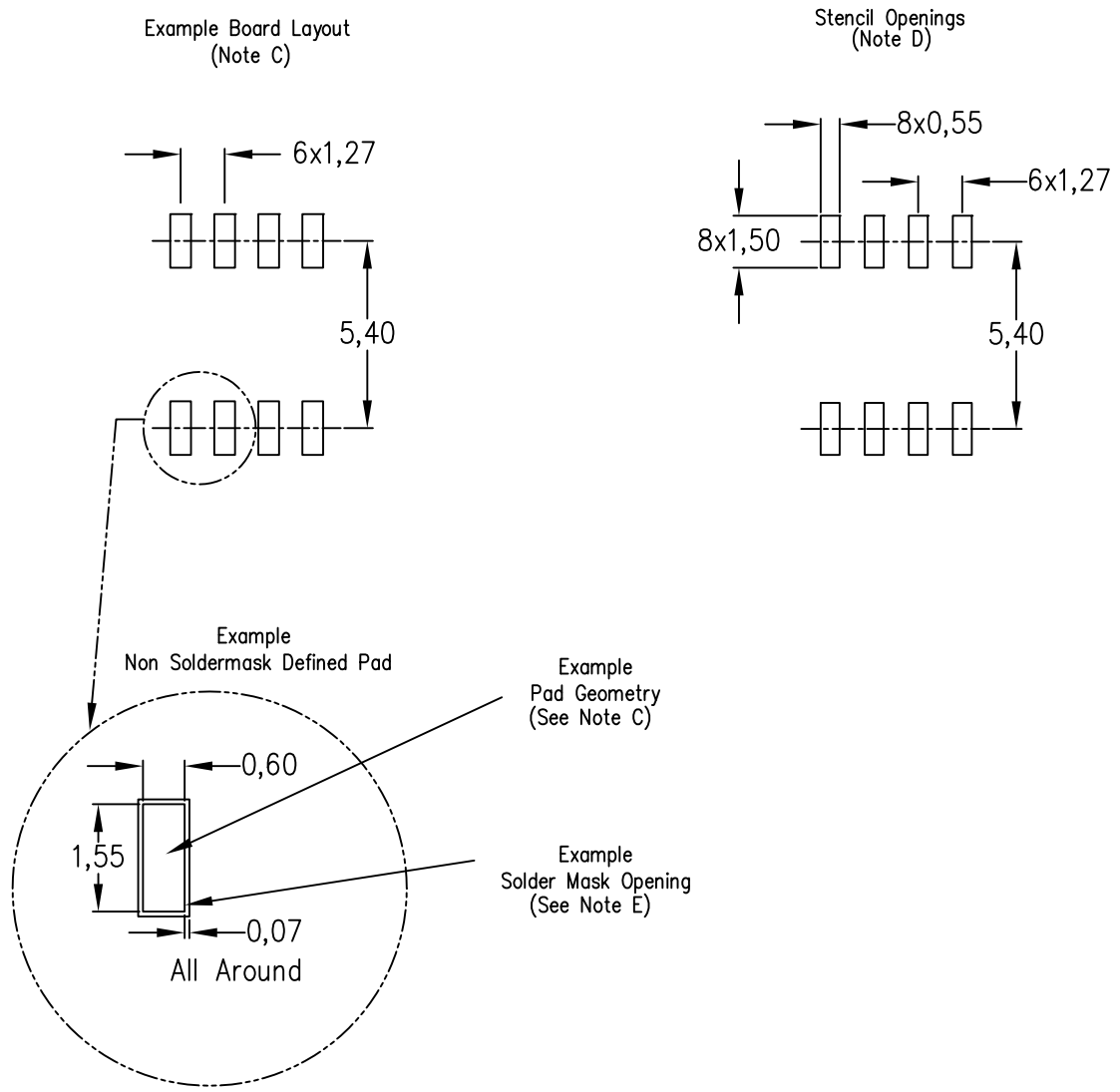
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
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E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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